

View Online at <https://aerobasegroup.com/nsn/5961-01-022-9194>

Inclosure Material:

Glass or metal or ceramic

Overall Length:

0.785 inches

Overall Height:

0.180 inches

Overall Width:

0.280 inches

Function For Which Designed:

Switching

Component Name And Quantity:

4 transistor

Mounting Method:

Press fit

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

80.0 collector to base voltage/static/emitter open all transistor and 50.0 collector to emitter voltage/static/base open all transistor and 6.0 emitter to base voltage, static, collector open all transistor

Current Rating Per Characteristic:

1.00 amperes source cutoff current all transistor

Power Rating Per Characteristic:

800.0 milliwatts small-signal input power, common-collector preset all transistor

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

All transistor junction pattern arrangement: npn

Precious Material And Location:

Leads silver or leads plated gold

Test Data Document:

80063-sm-a-742219 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

14 ribbon

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0